

*Spring 2019 Purdue University*

# **ECE 255: L5**

# **Energy Band Diagrams**

Mark Lundstrom  
School of ECE  
Purdue University  
West Lafayette, IN USA

Lundstrom: 2019

# Energy band diagrams

---

- 1) Band bending and the electrostatic potential
- 2) “Reading” an energy band diagram
- 3) PN junctions
- 4) Energy band diagram of a PN junction in equilibrium
- 5) Forward bias and reverse bias
- 6) The built-in potential

# Energy band diagrams

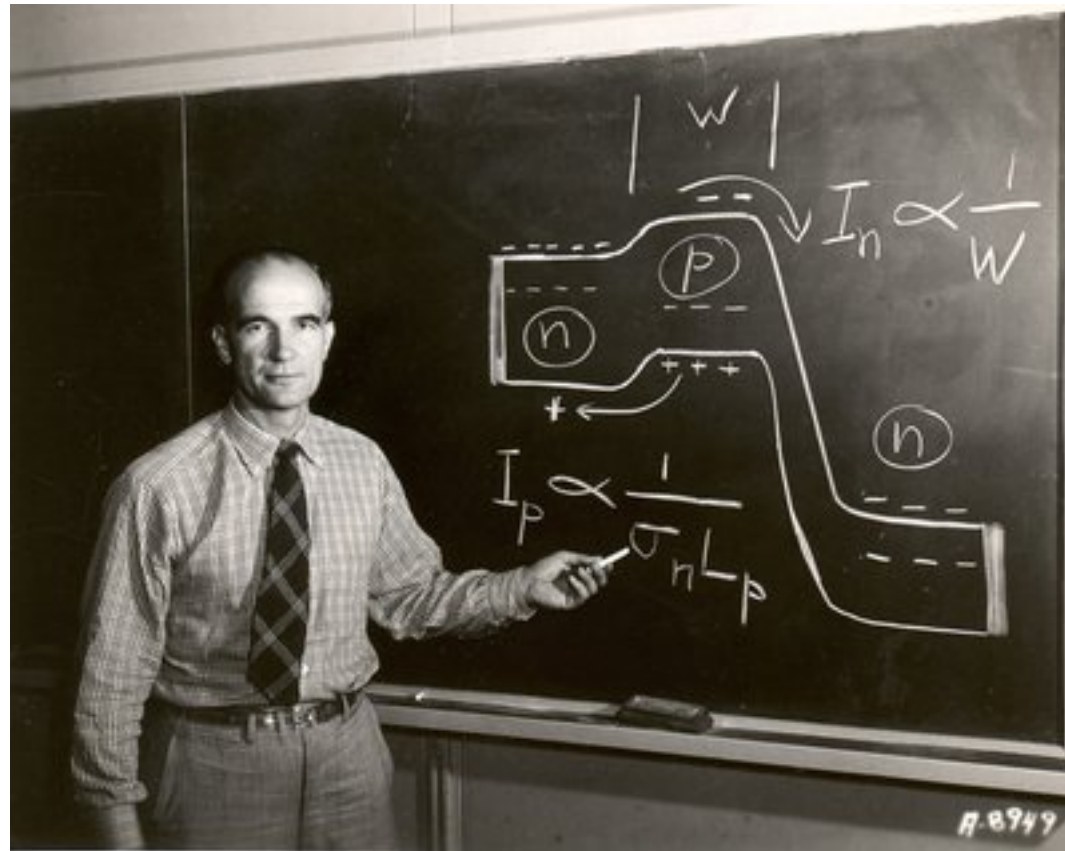
---

An energy band diagram is a plot of the bottom of the conduction band and the top of the valence band vs. position.

Energy band diagrams are a powerful tool for understanding semiconductor devices because they provide **qualitative solutions to the semiconductor equations.**

# Energy band diagrams

---



## Kroemer's lemma of proven ignorance

---

“Whenever I teach my semiconductor device physics course, one of the central messages I try to get across early is the importance of energy band diagrams. I often put this in the form of “Kroemer's lemma of proven ignorance:

If, in discussing a semiconductor problem, you cannot draw an **Energy Band Diagram**, this shows that **you** don't know what you are talking about.”

(Nobel Lecture, 2000)

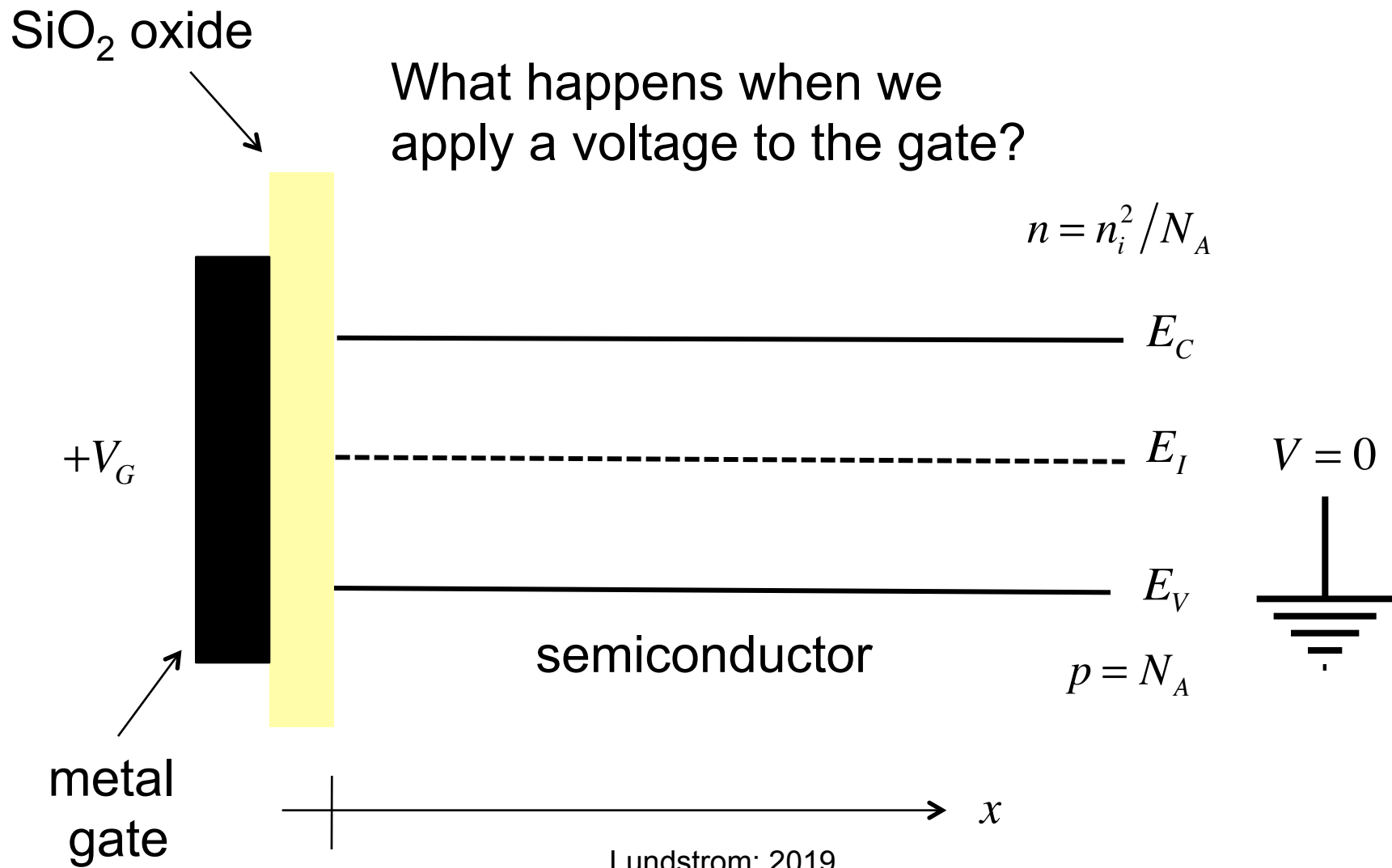
# Kroemer's corollary

---

If you can draw one, but don't, then **your audience** won't know what you are talking about."

(Nobel Lecture, 2000)

# Band bending in an MOS structure



# Voltage and electron potential energy

---

$$E = -qV$$



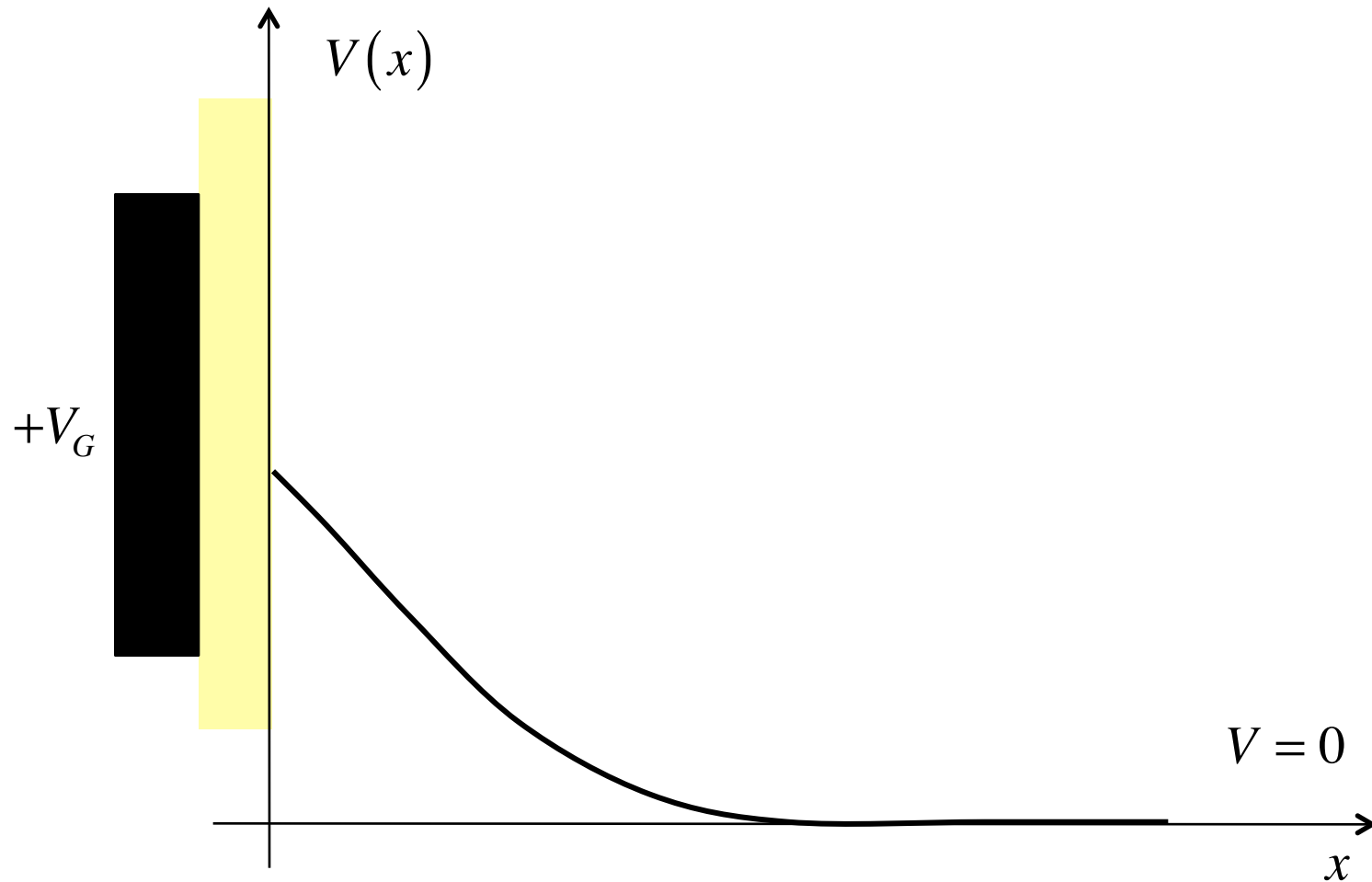
$+V$

A positive potential **lowers** the energy of an electron.

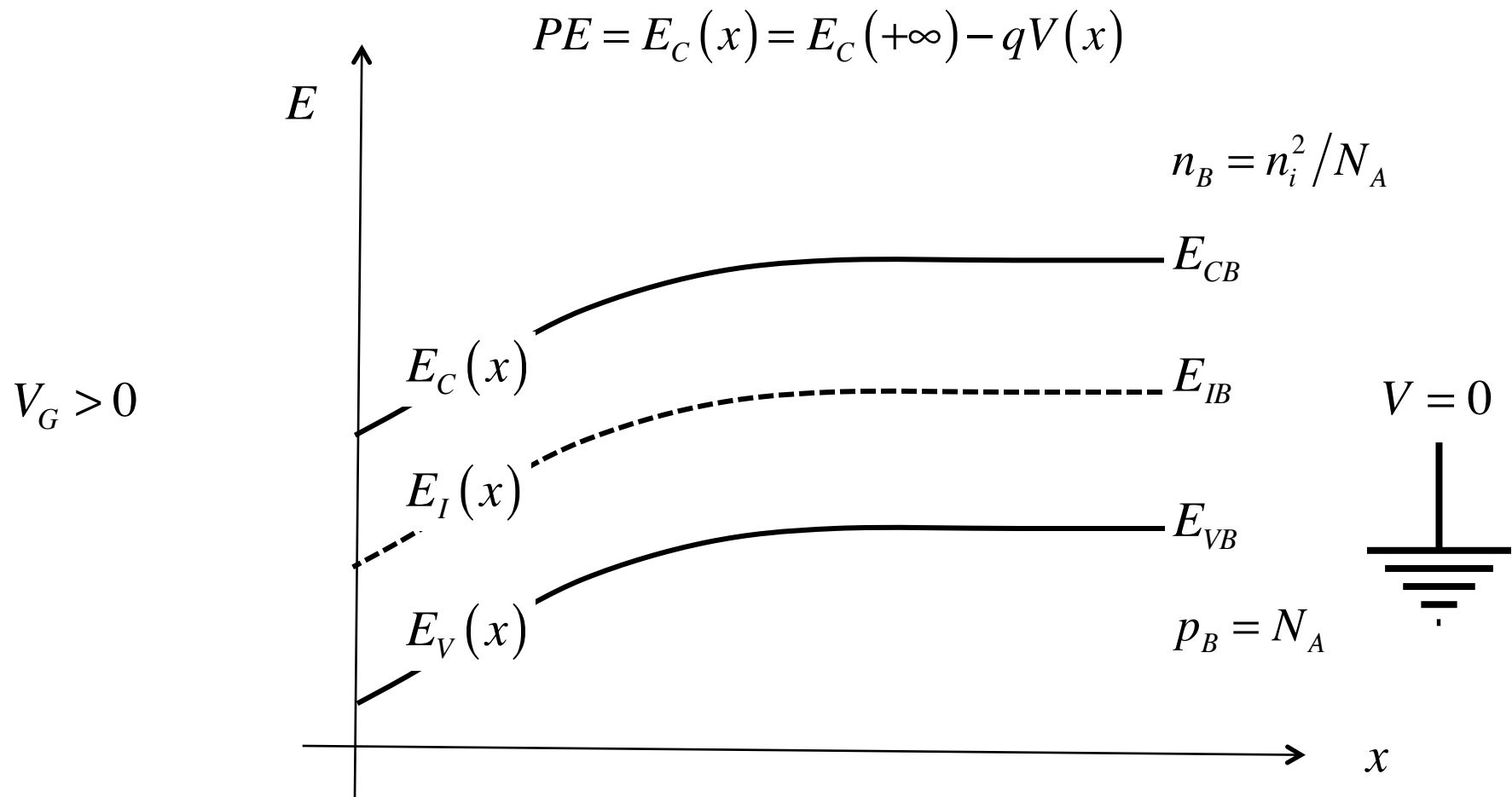


# Electrostatic potential vs. position

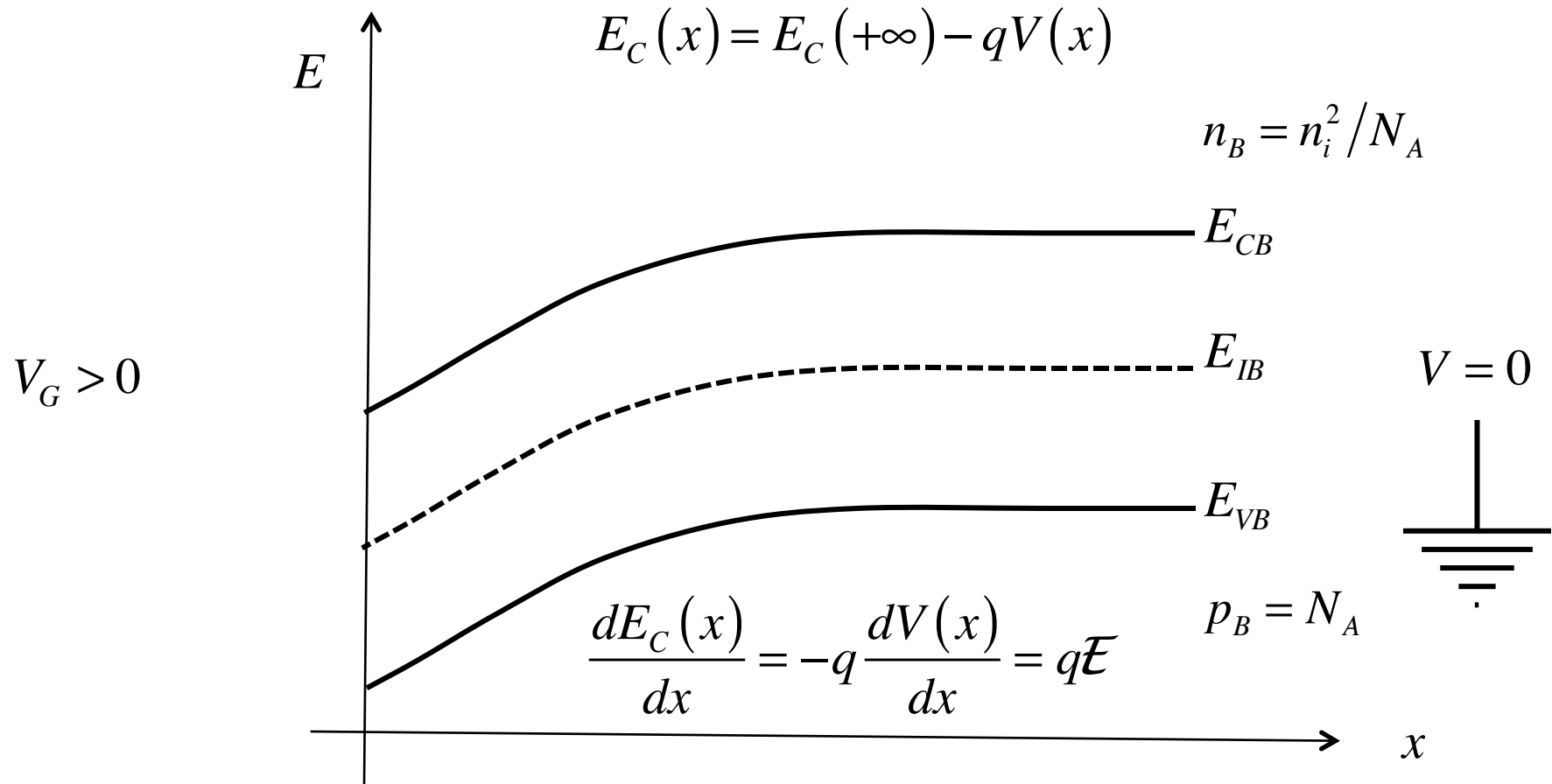
---



# Electrostatic potential causes band bending



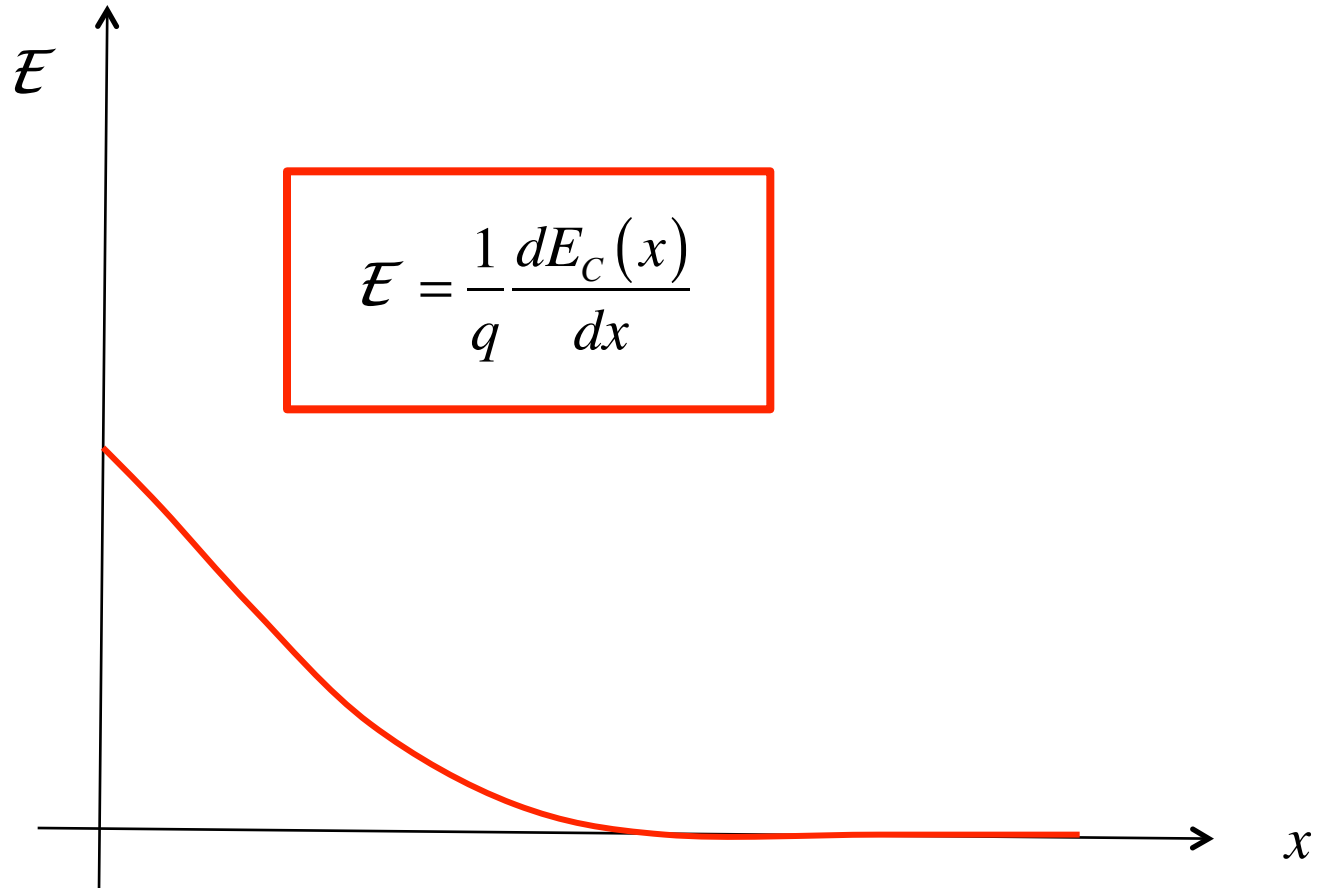
# Electric field



The electric field is proportional to the slope of  $E_C$  11

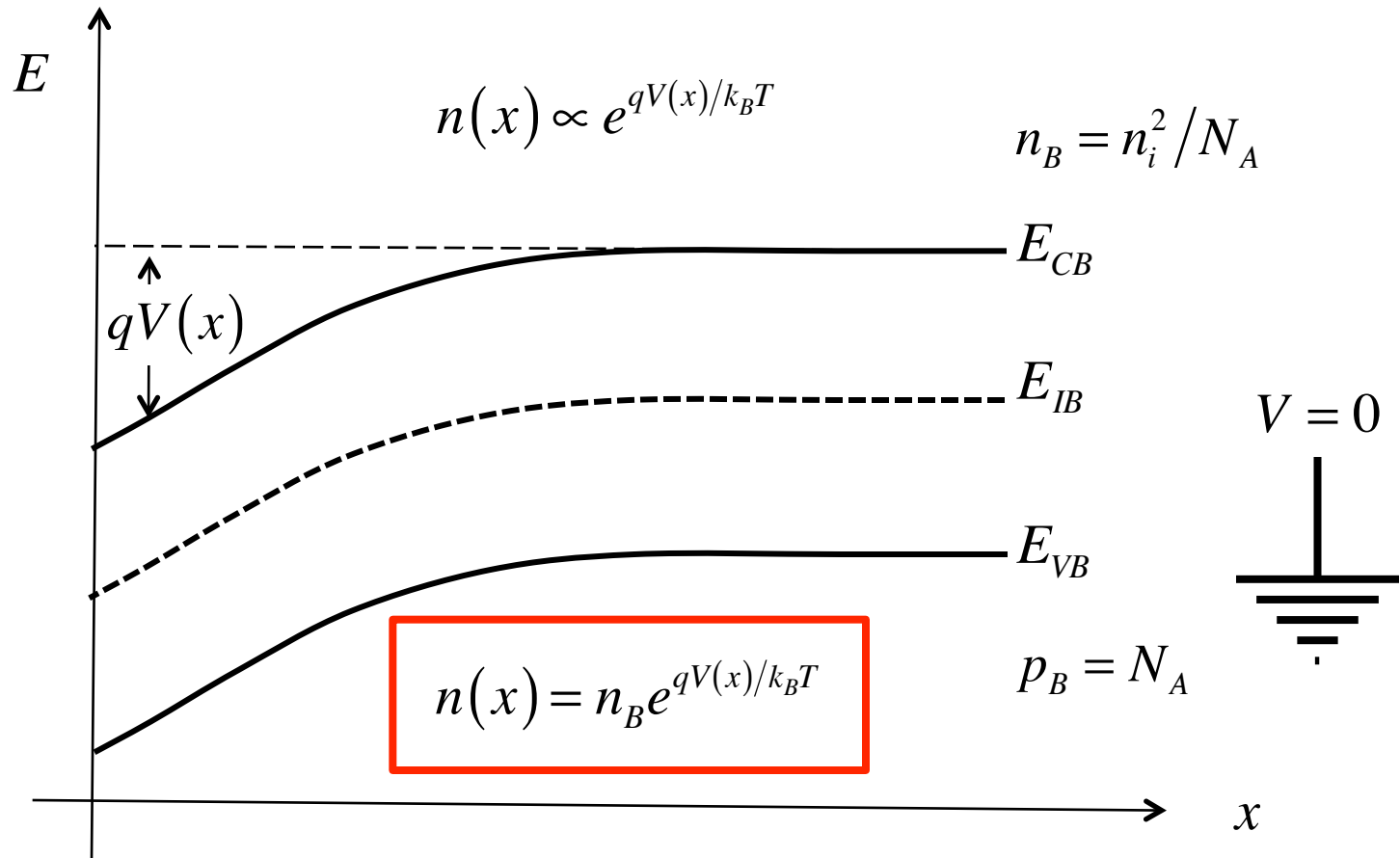
# Electric field

---



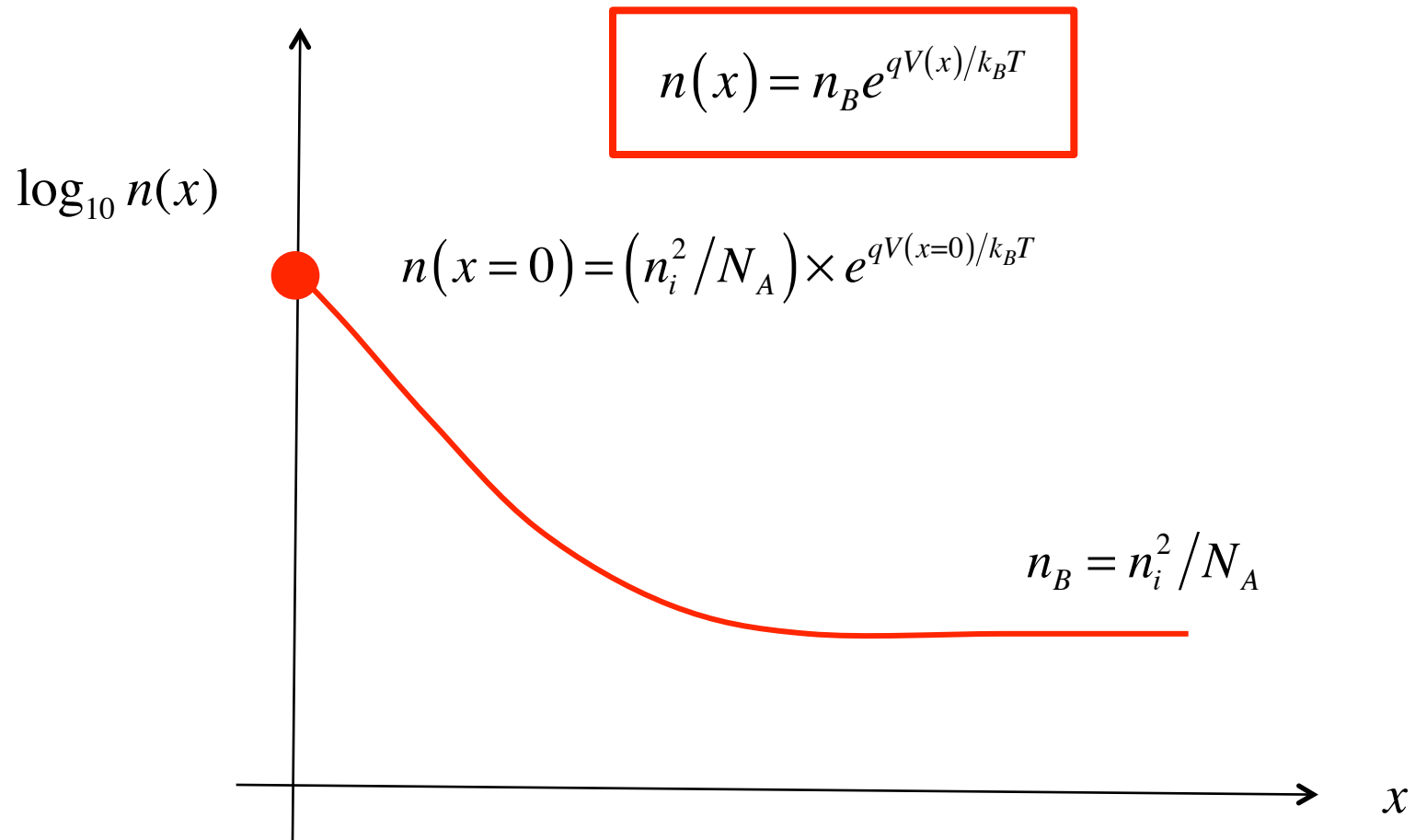
The electric field is proportional to the slope of  $E_c$

# Electron concentration

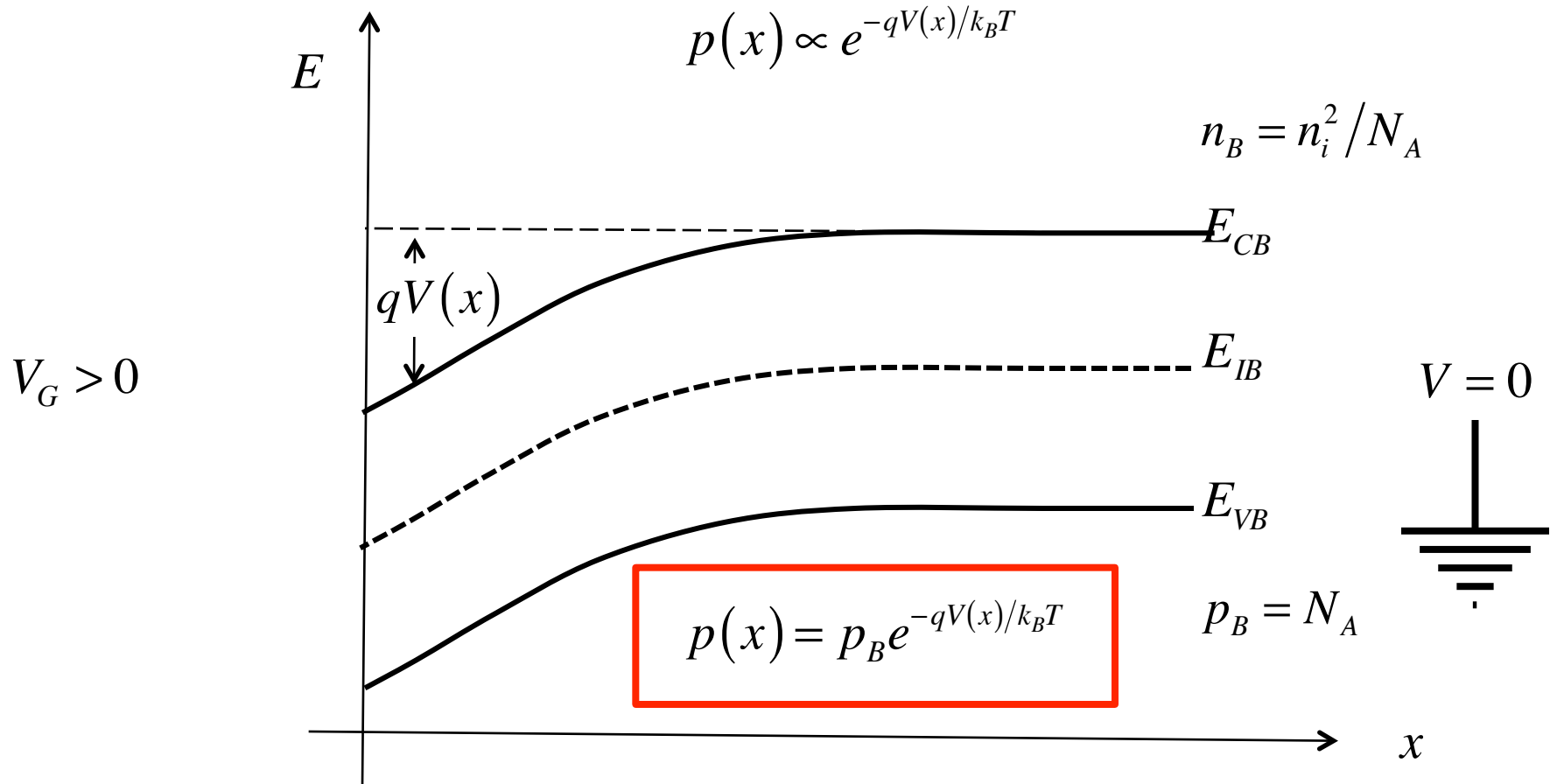


# Electron concentration

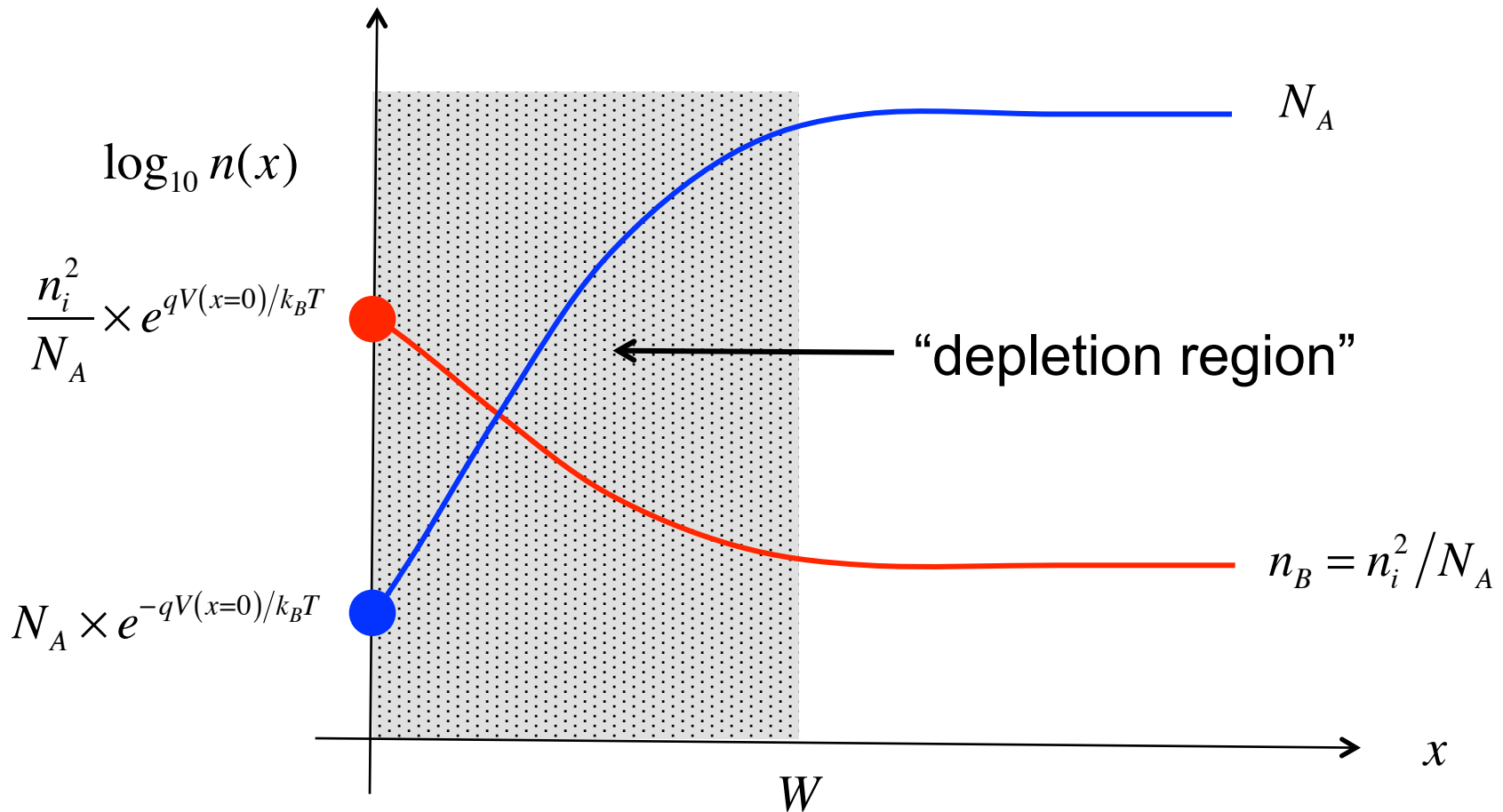
---



# Hole concentration



# Electron and hole concentrations

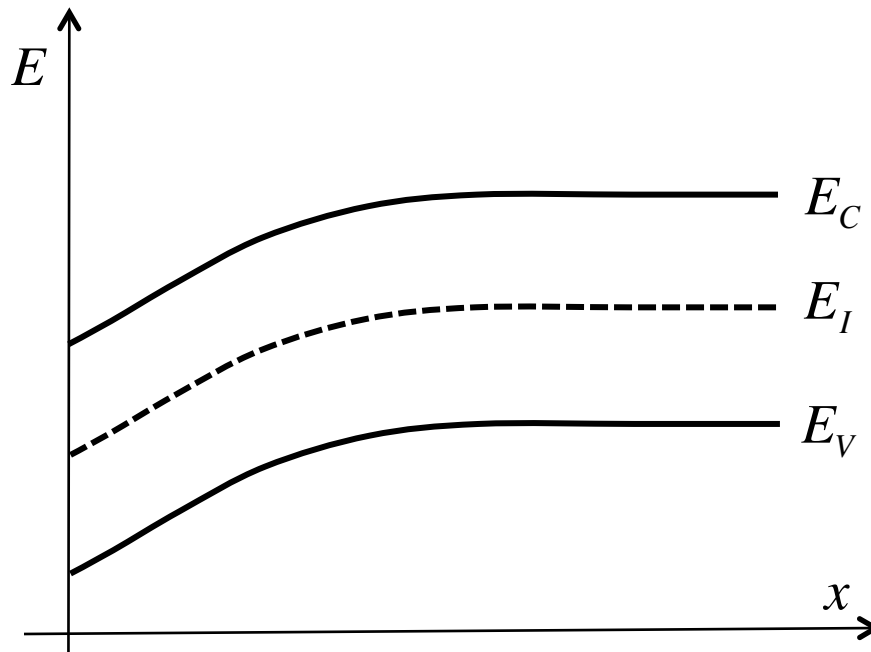




# Summary: Band diagrams

---

A band diagram



Reading the band diagram

$$V(x) \propto -E_C(x)$$

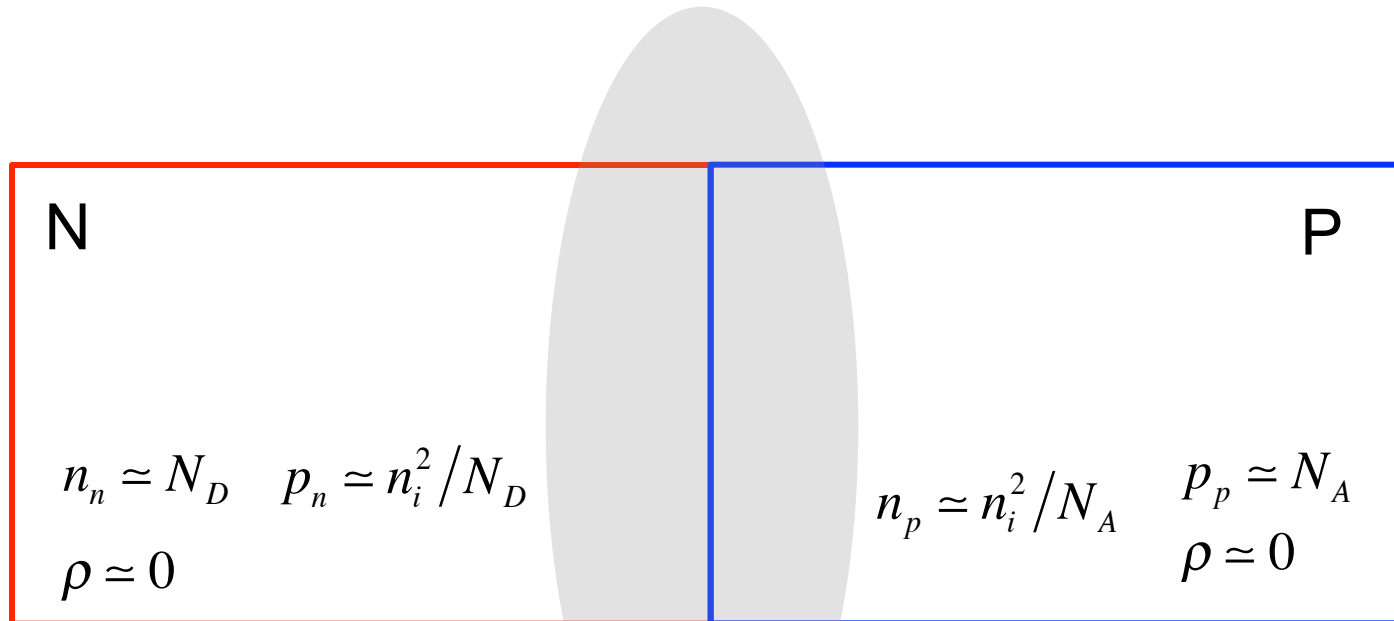
$$\mathcal{E} \propto dE_C(x)/dx$$

$$\log n(x) \propto E_{CB} - E_C(x)$$

$$\log p(x) \propto E_V(x) - E_{VB}$$

# Another example: NP junction (equilibrium)

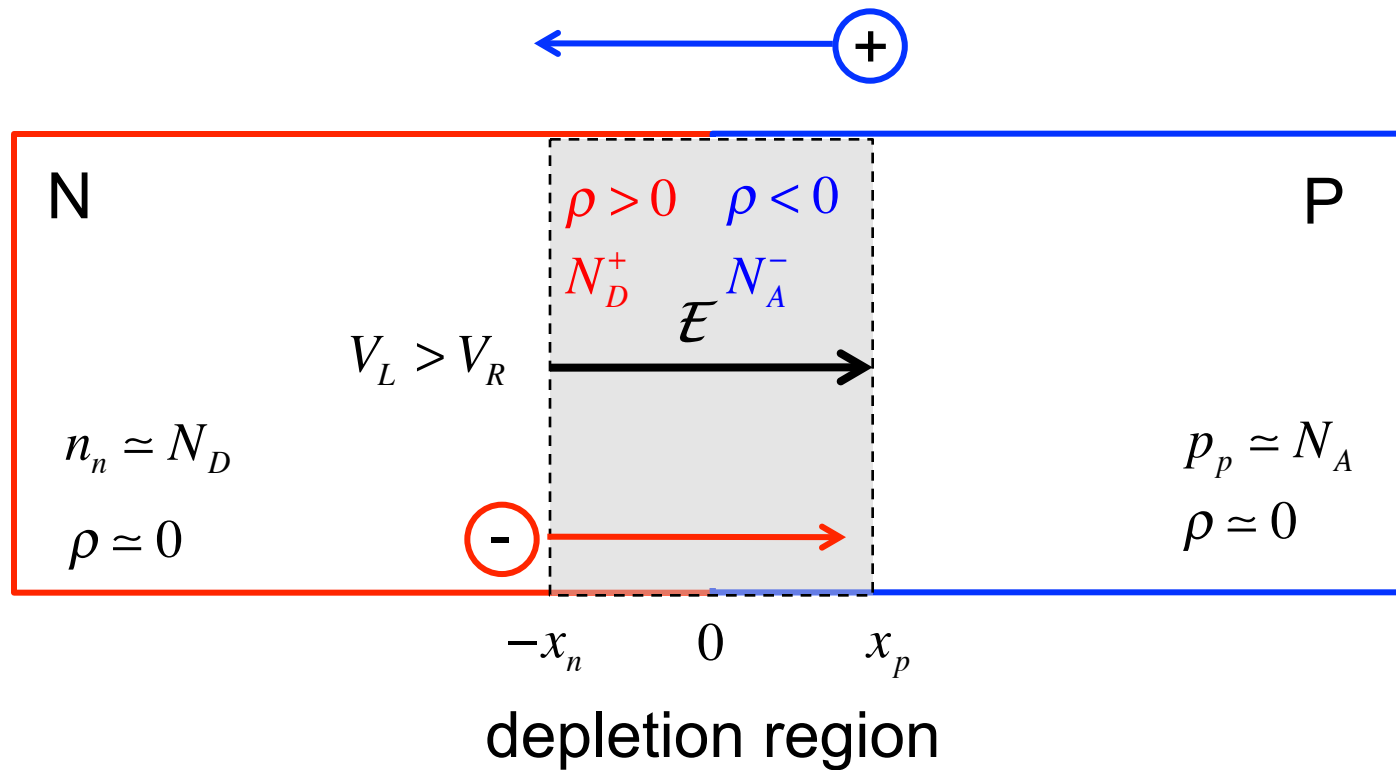
---



“majority carriers”

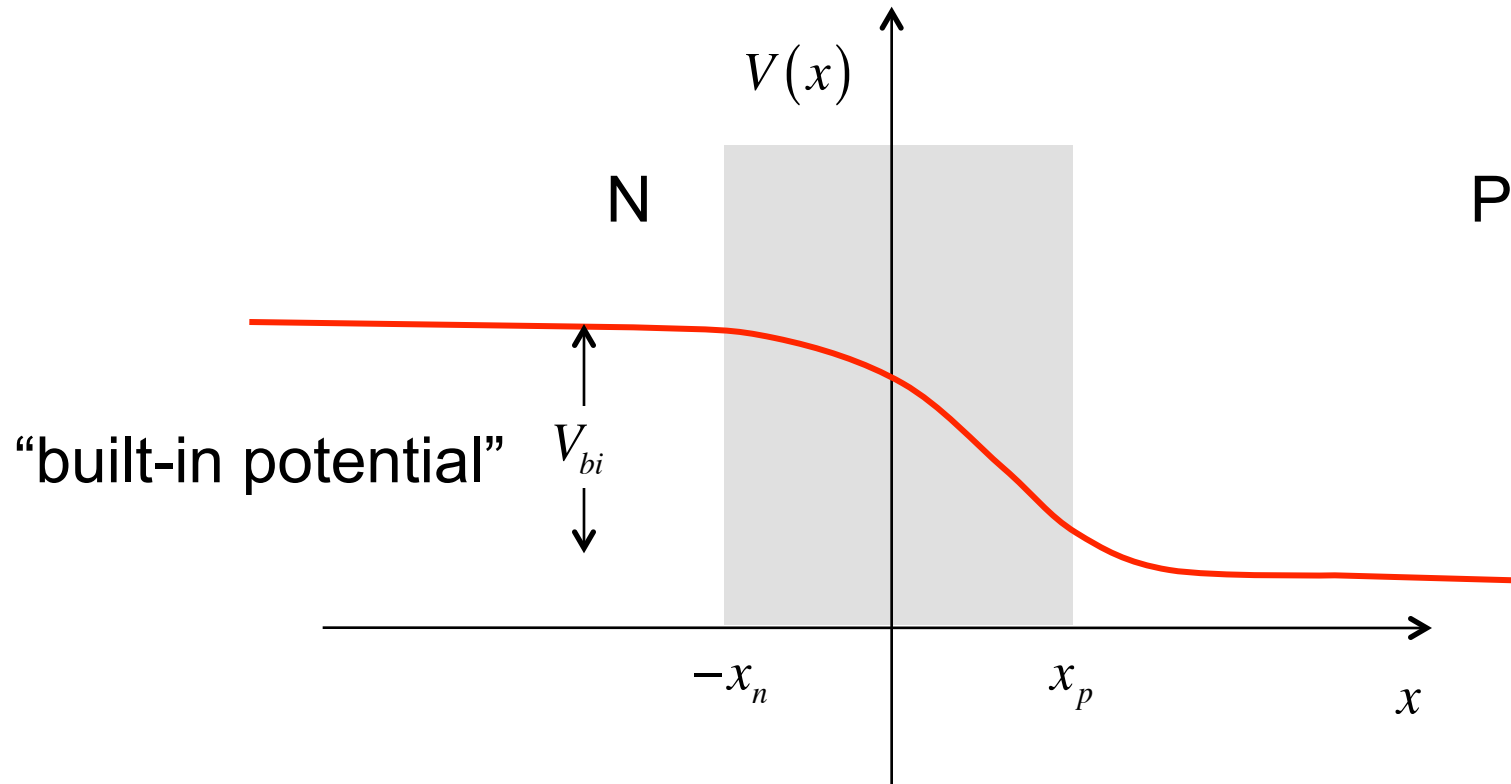
“minority carriers”

# NP junction (equilibrium)

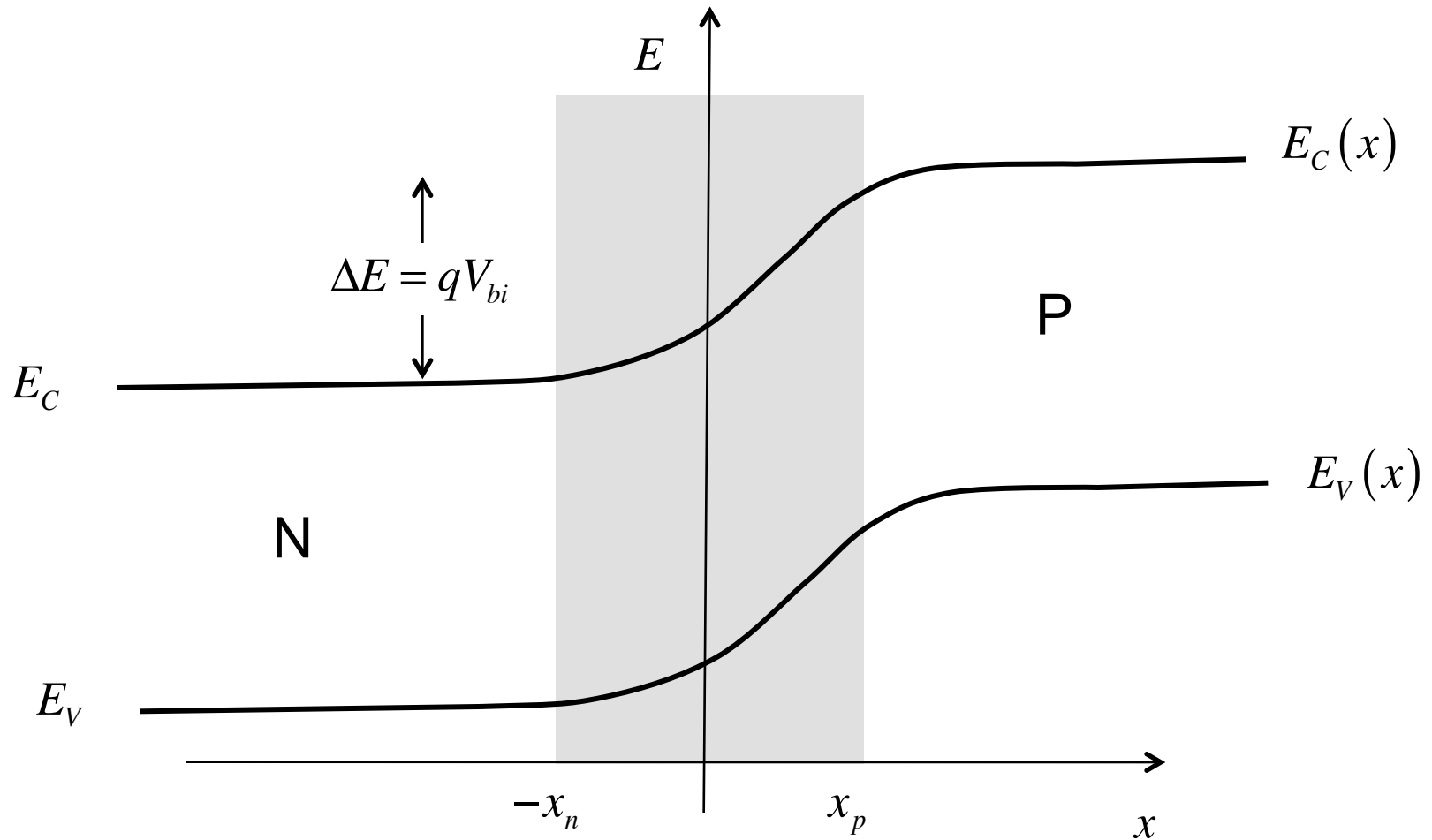


# Voltage vs. position

---

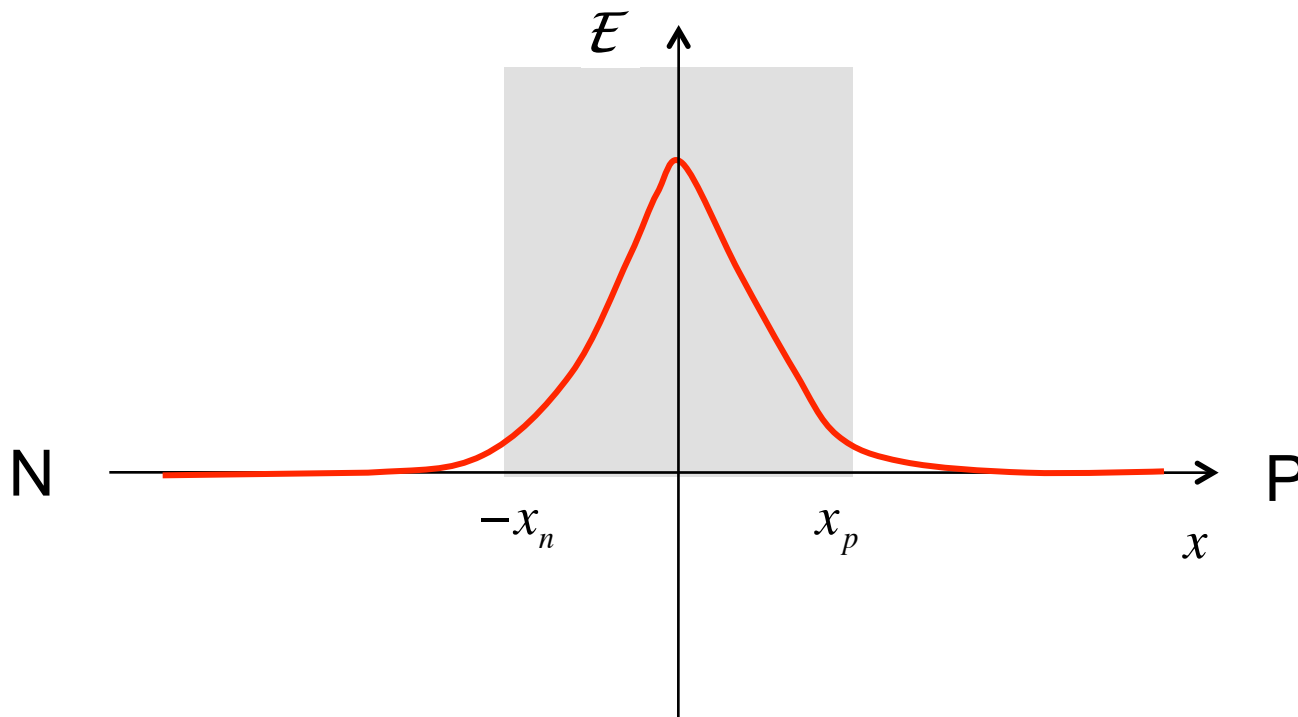


# Electron energy vs. position

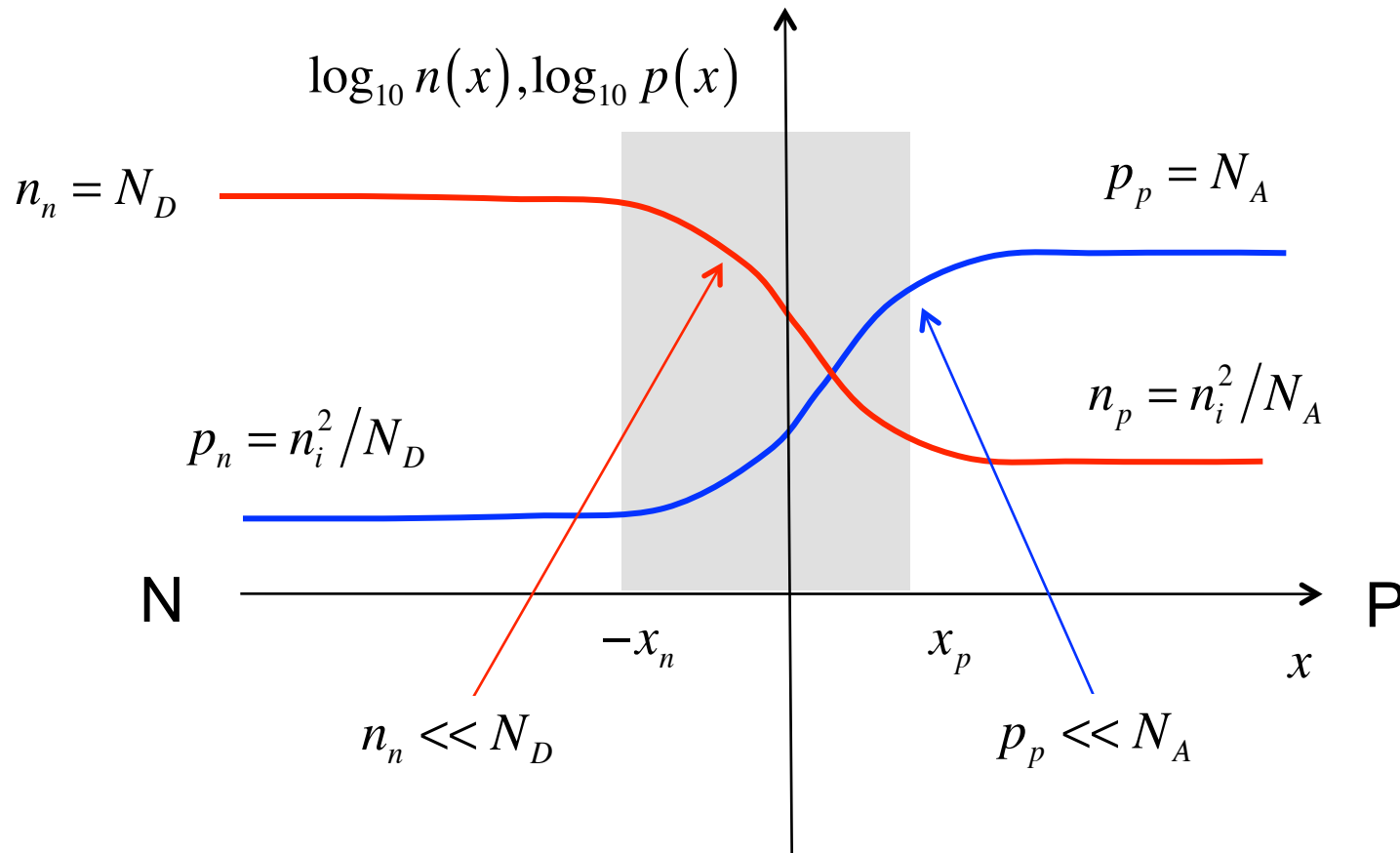


# Electric field vs. position

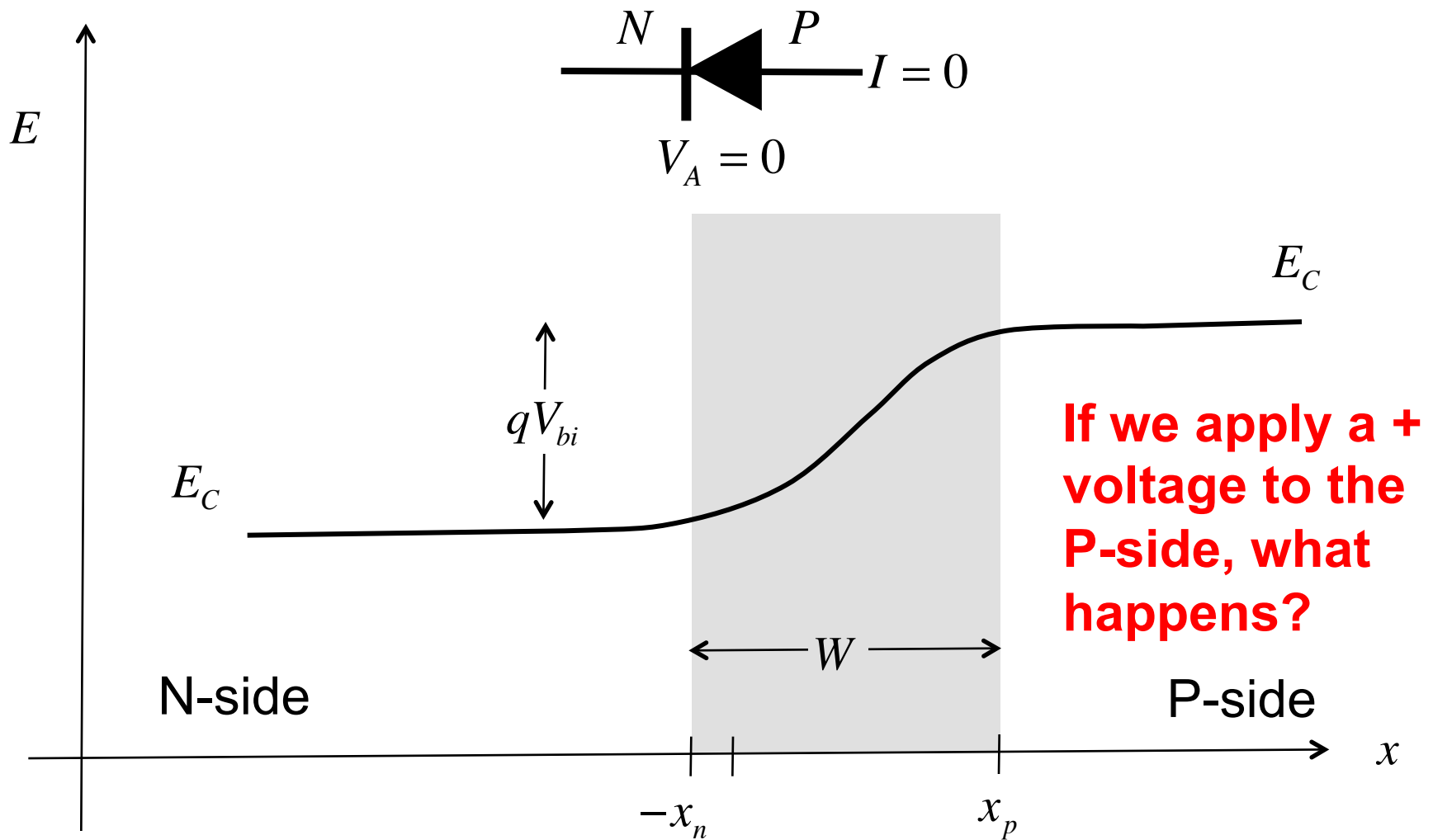
---



# Carrier densities vs. position



# Equilibrium energy band diagram

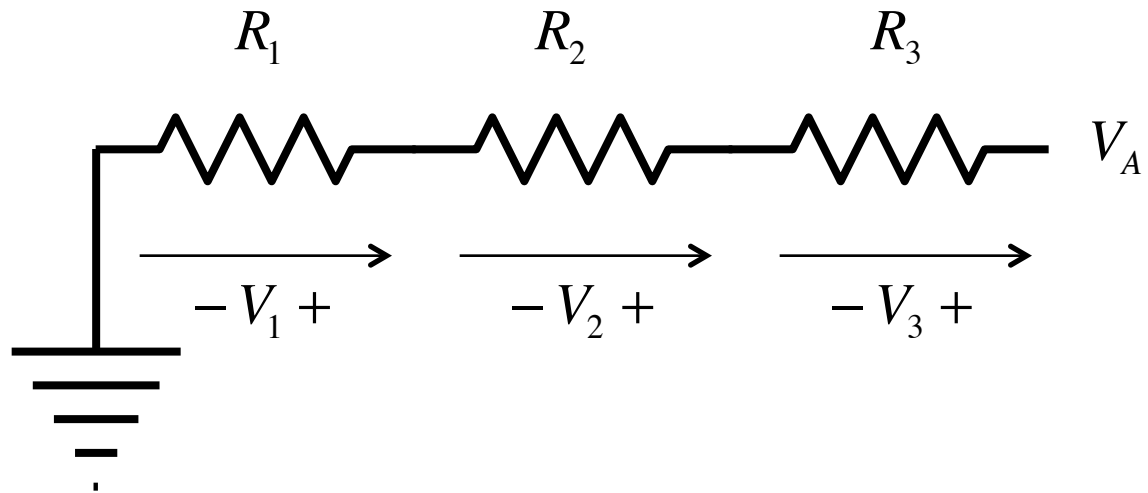




# Where does the voltage drop?

---

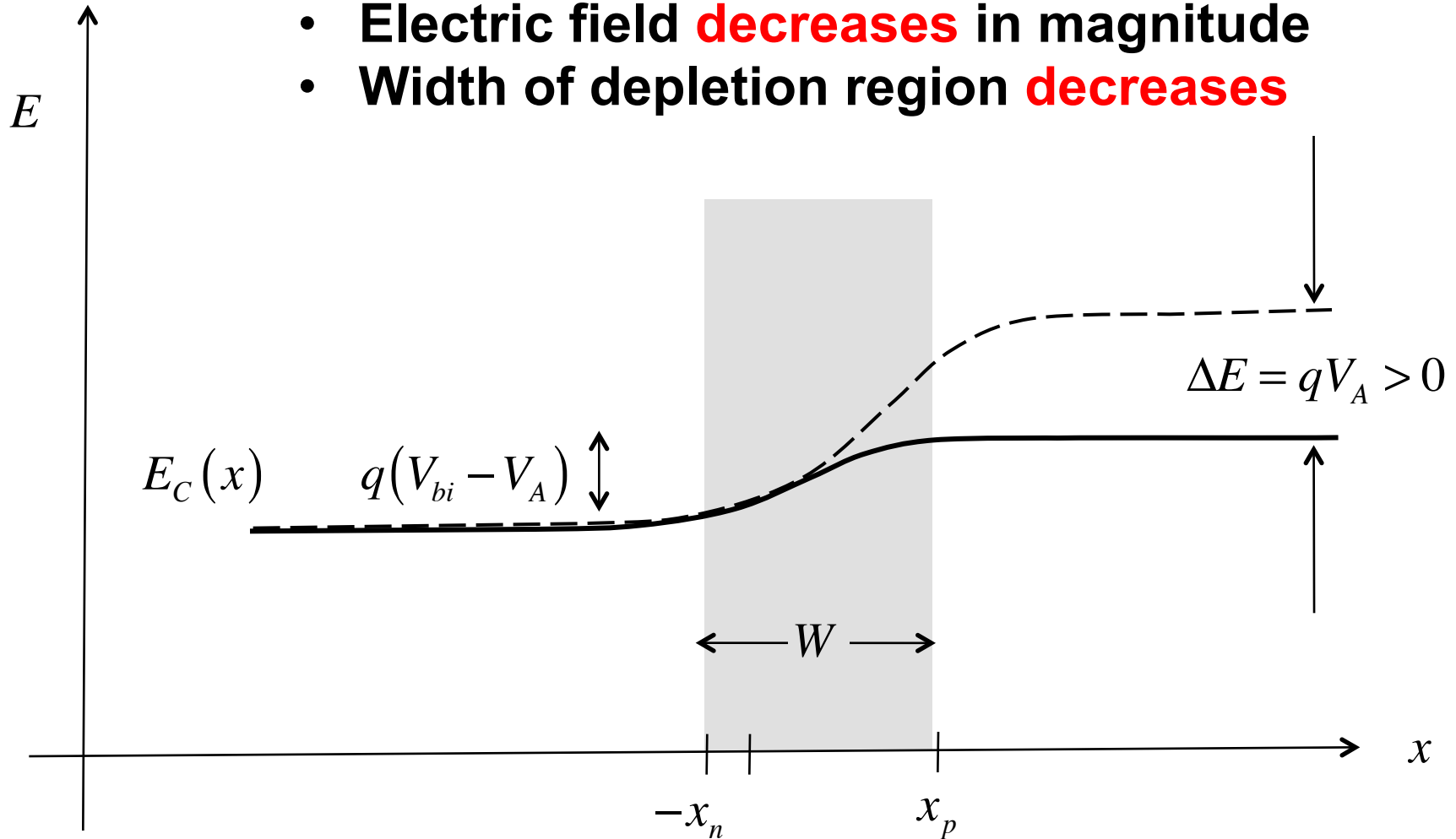
$$R_2 \gg R_1, R_3$$



$$V_2 \approx ?$$

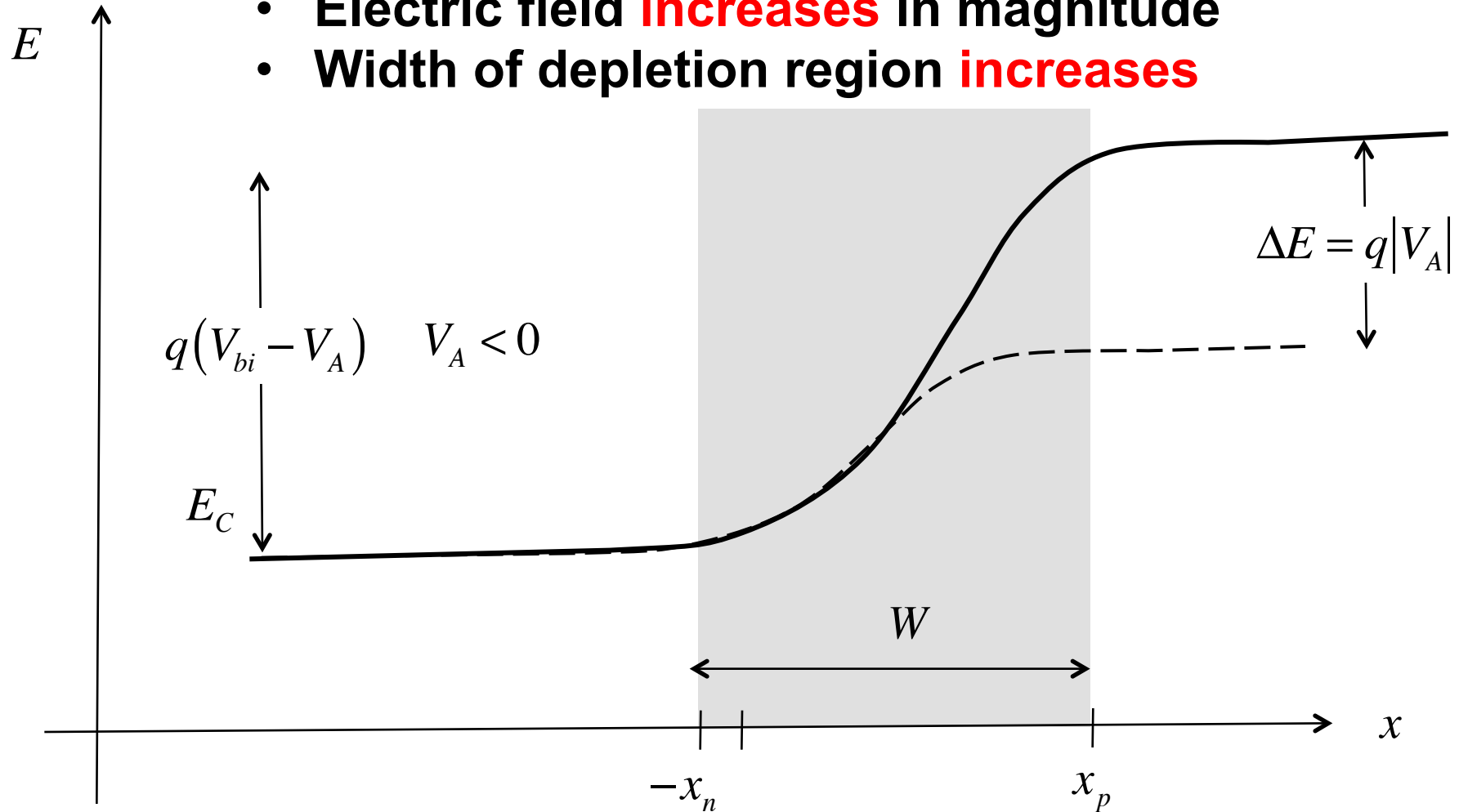
# Forward bias $\rightarrow$ smaller energy barrier

- Electric field **decreases** in magnitude
- Width of depletion region **decreases**

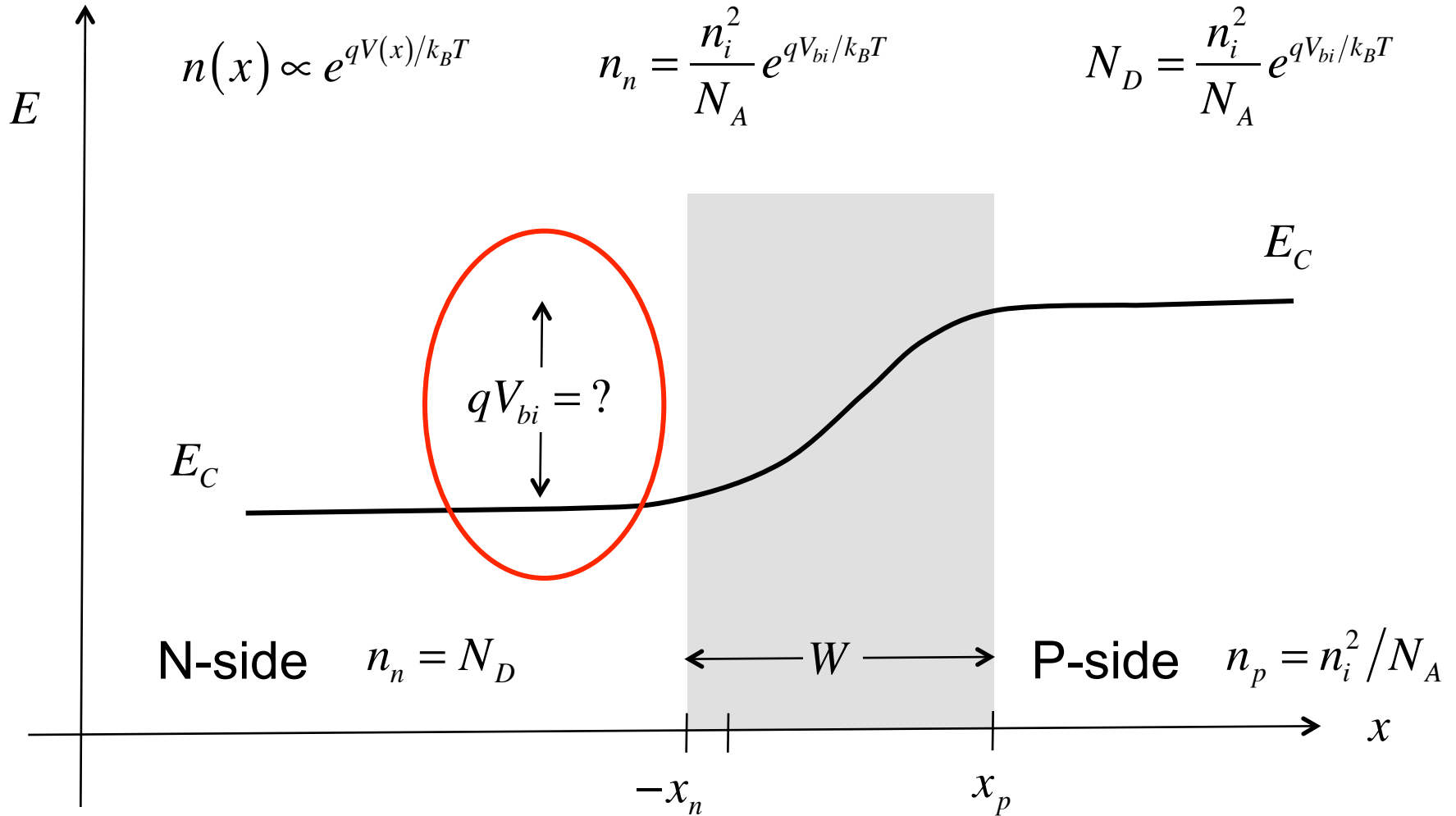


# Reverse bias $\rightarrow$ larger energy barrier

- Electric field **increases** in magnitude
- Width of depletion region **increases**

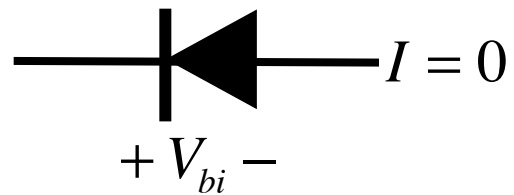


# Equilibrium built-in potential



# Equilibrium built-in potential

---



$$V_{bi} = \frac{k_B T}{q} \ln \left( \frac{N_A N_D}{n_i^2} \right)$$

# Summary

---

Energy band diagrams are a powerful tool for understanding the operation of semiconductor devices.

To find the electrostatic potential vs. position, turn  $E_C(x)$  upside down.

To find the electric field vs. position, take the slope of  $E_C(x)$ .

To find the carrier density vs. position, begin where it is known, and then exponentially increase or decrease according to the local electrostatic potential.

# Energy band diagrams

---

- 1) Band bending and the electrostatic potential
- 2) “Reading” an energy band diagram
- 3) PN junctions
- 4) Energy band diagram of a PN junction in equilibrium
- 5) Forward bias and reverse bias
- 6) The built-in potential

